

FS18KM-9A

HIGH-SPEED SWITCHING USE

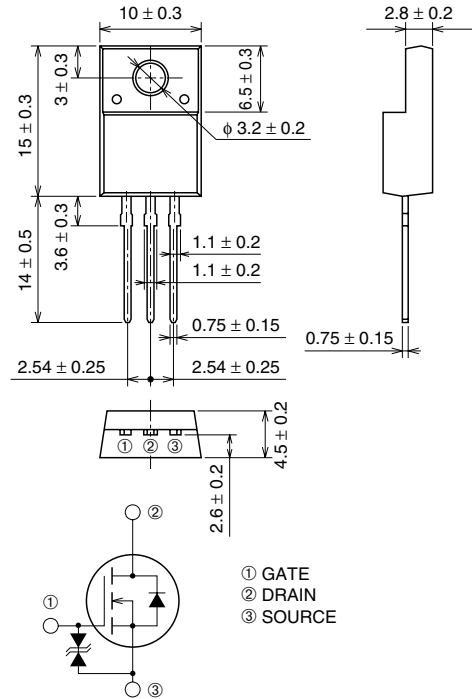
FS18KM-9A



- 10V DRIVE
- V_{DS} 450V
- $r_{DS(ON)}$ (MAX) 0.30Ω
- I_D 18A

OUTLINE DRAWING

Dimensions in mm



TO-220FN

APPLICATION

SMPS, AC-adaptor, Power supply of Printer, Copier, TV, VCR. etc.

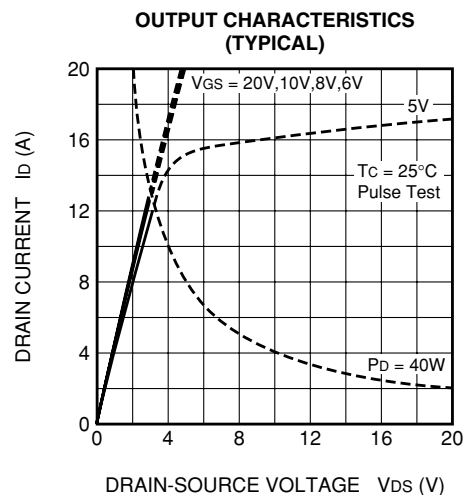
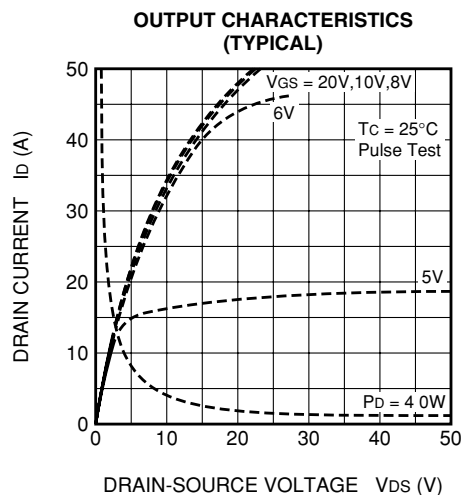
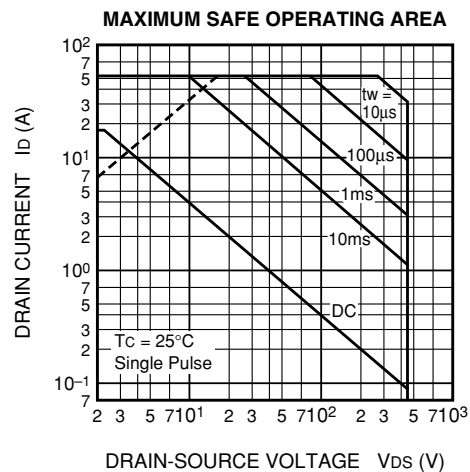
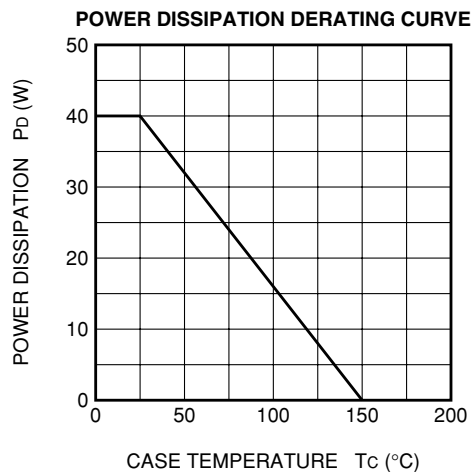
MAXIMUM RATINGS (T_c = 25°C)

Symbol	Parameter	Conditions	Ratings	Unit
V_{DS}	Drain-source voltage	$V_{GS} = 0V$	450	V
V_{GSS}	Gate-source voltage	$V_{DS} = 0V$	±30	V
I_D	Drain current		18	A
I_{DM}	Drain current (Pulsed)		54	A
I_{DA}	Avalanche current (Pulsed)	$L = 200\mu H$	18	A
P_D	Maximum power dissipation		40	W
T_{ch}	Channel temperature		-55 ~ +150	°C
T_{stg}	Storage temperature		-55 ~ +150	°C
V_{iso}	Isolation voltage	AC for 1minute, Terminal to case	2000	V
—	Weight	Typical value	2.0	g

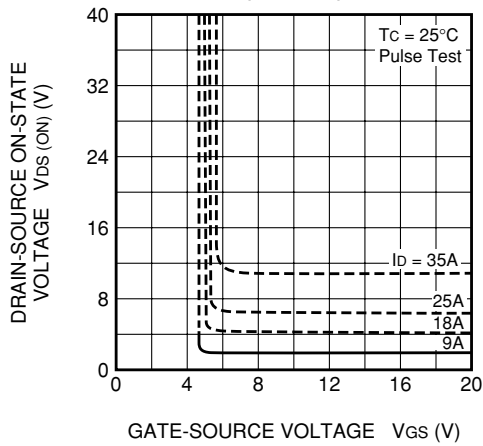
ELECTRICAL CHARACTERISTICS ($T_{ch} = 25^{\circ}\text{C}$)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
$V_{(BR)DSS}$	Drain-source breakdown voltage	$I_D = 1\text{mA}$, $V_{GS} = 0\text{V}$	450	—	—	V
$V_{(BR)GSS}$	Gate-source breakdown voltage	$I_{GS} = \pm 100\mu\text{A}$, $V_{DS} = 0\text{V}$	± 30	—	—	V
I_{GSS}	Gate-source leakage current	$V_{GS} = \pm 25\text{V}$, $V_{DS} = 0\text{V}$	—	—	± 10	μA
I_{DSS}	Drain-source leakage current	$V_{DS} = 450\text{V}$, $V_{GS} = 0\text{V}$	—	—	1	mA
$V_{GS(th)}$	Gate-source threshold voltage	$I_D = 1\text{mA}$, $V_{DS} = 10\text{V}$	2.5	3.0	3.5	V
$r_{DS(on)}$	Drain-source on-state resistance	$I_D = 9\text{A}$, $V_{GS} = 10\text{V}$	—	0.26	0.30	Ω
$V_{DS(on)}$	Drain-source on-state voltage	$I_D = 9\text{A}$, $V_{GS} = 10\text{V}$	—	2.34	2.70	V
$ y_{fs} $	Forward transfer admittance	$I_D = 9\text{A}$, $V_{DS} = 10\text{V}$	10.8	18.0	—	S
C_{iss}	Input capacitance	$V_{DS} = 25\text{V}$, $V_{GS} = 0\text{V}$, $f = 1\text{MHz}$	—	2350	—	pF
C_{oss}	Output capacitance		—	260	—	pF
C_{rss}	Reverse transfer capacitance		—	50	—	pF
$t_{d(on)}$	Turn-on delay time	$V_{DD} = 200\text{V}$, $I_D = 9\text{A}$, $V_{GS} = 10\text{V}$, $R_{GEN} = R_{GS} = 50\Omega$	—	35	—	ns
t_r	Rise time		—	55	—	ns
$t_{d(off)}$	Turn-off delay time		—	310	—	ns
t_f	Fall time		—	70	—	ns
V_{SD}	Source-drain voltage	$I_S = 9\text{A}$, $V_{GS} = 0\text{V}$	—	1.5	2.0	V
$R_{th(ch-c)}$	Thermal resistance	Channel to case	—	—	3.12	$^{\circ}\text{C/W}$

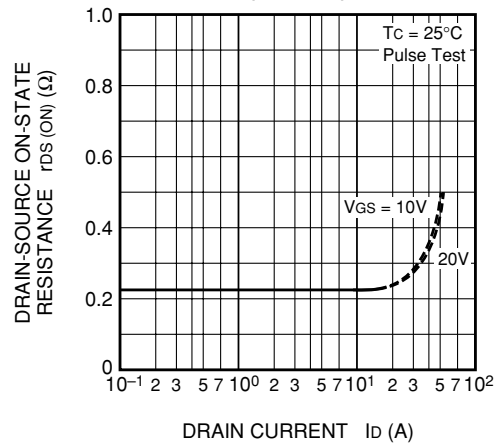
PERFORMANCE CURVES



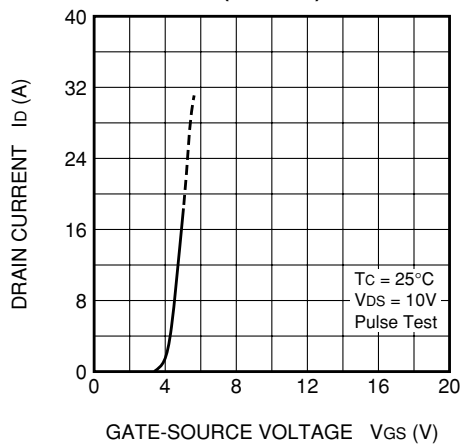
ON-STATE VOLTAGE VS.
GATE-SOURCE VOLTAGE
(TYPICAL)



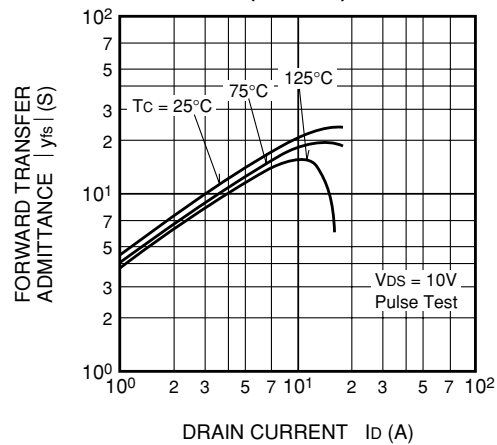
ON-STATE RESISTANCE VS.
DRAIN CURRENT
(TYPICAL)



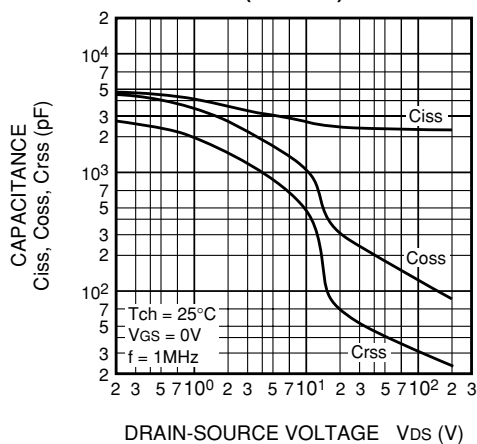
TRANSFER CHARACTERISTICS
(TYPICAL)



FORWARD TRANSFER ADMITTANCE
VS. DRAIN CURRENT
(TYPICAL)



CAPACITANCE VS.
DRAIN-SOURCE VOLTAGE
(TYPICAL)



SWITCHING CHARACTERISTICS
(TYPICAL)

